



LOW VCE(SAT) NPN TRANSISTOR IN SOT223

Features

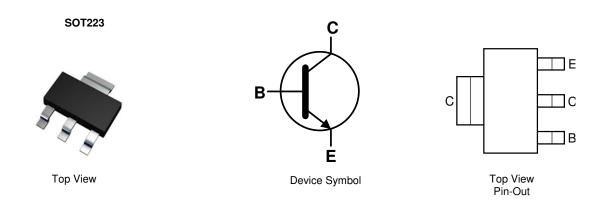
- BV_{CEO} > 60V
- I_C = 3.0A High Continuous Current
- Extremely Low Equivalent On-Resistance; R_{CE(SAT)} 62mΩ at 2A
- Complementary PNP Type: DPLS350E
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

Applications

Ideal for Medium Power Switching or Amplification Applications



Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DNLS350E-13	AEC-Q101	N35	13	12	2,500

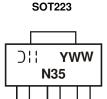
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



N35 = Product Type Marking Code YWW = Date Code Marking Y = Last Digit of Year (ex: 15 = 2015) WW = Week Code (01 - 52)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	6	V
Continuous Collector Current	Ic	3	A
Peak Pulse Collector Current	I _{CM}	5	A
Peak Pulse Base Current	I _{BM}	1	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
	(Note 5)		3	
Power Dissipation	(Note 6)	PD	2	W
	(Note 7)		1	
	(Note 5)		41.7	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	62.5	°C/W
	(Note 7)		125	
Thermal Resistance, Junction to Leads	(Note 8)	$R_{\theta JL}$	15	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C	

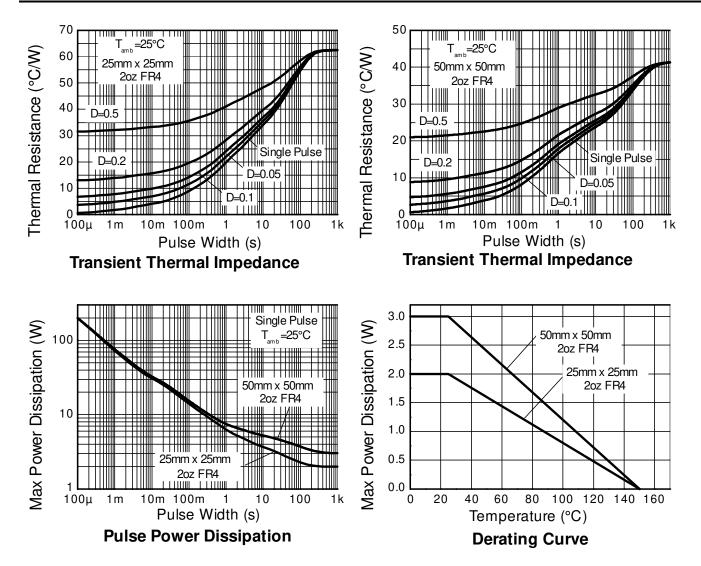
ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Same as Note (5), except mounted on 25mm x 25mm 2oz copper.
7. Same as Note (5), except mounted on minimum recommended pad (MRP) layout.
8. Thermal resistance from junction to solder-point (at the end of the collector lead).
9. Refer to JEDEC specification JESD22-A114 and JESD22-A115. Notes:



Thermal Characteristics and Derating Information

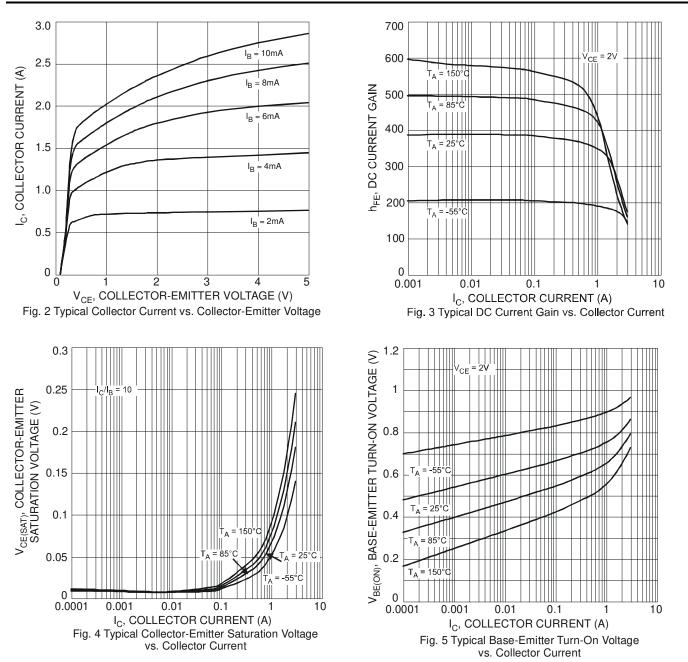




Electrical Characteristics (@T_A = +25°C, unless otherwise specified.) Characteristic Symbol Min Тур Max Unit **Test Conditions** OFF CHARACTERISTICS Collector-Base Breakdown Voltage 50 V $\mathsf{BV}_{\mathsf{CBO}}$ $I_{\rm C} = 100 \mu A$ Collector-Emitter Breakdown Voltage (Note 10) $\mathsf{BV}_{\mathsf{CEO}}$ 50 ٧ $I_{\rm C} = 10 {\rm mA}$ $\mathsf{BV}_{\mathsf{EBO}}$ Emitter-Base Breakdown Voltage 6 V $I_E = 100 \mu A$ 100 nA $V_{CB}=50V,\,I_E=0$ ____ ____ Collector-Base Cutoff Current I_{CBO} $V_{CB} = 50V, \ \overline{I_E = 0, \ T_A = +150^{\circ}C}$ 50 μΑ ____ ____ Emitter-Base Cutoff Current 100 nA $V_{EB} = 5V, I_{C} = 0$ **I**EBO ____ ____ **ON CHARACTERISTICS** (Note 10) 200 $V_{CE} = 2V, I_{C} = 0.5A$ ____ ____ DC Current Gain 200 h_{FE} ____ ____ $V_{CE} = 2V, I_{C} = 1A$ 100 $V_{CE}=2V,\,I_C=2A$ ____ 90 $I_{C} = 0.5A, I_{B} = 50mA$ Collector-Emitter Saturation Voltage V_{CE(SAT)} 170 mV $I_{C} = 1A, I_{B} = 50mA$ 290 $I_{C} = 2A, I_{B} = 200mA$ Equivalent On-Resistance RCE(SAT) 62 145 mΩ $I_{C} = 2A, I_{B} = 200mA$ Base-Emitter Saturation Voltage V_{BE(SAT)} 1.2 V $I_{C} = 2A, I_{B} = 200mA$ Base-Emitter Turn-On Voltage V_{BE(ON)} 1.1 ۷ $V_{CE} = 2V, I_C = 1A$ ____ ____ SMALL SIGNAL CHARACTERISTICS $V_{CE} = 5V, I_{C} = 100mA,$ Transition Frequency 100 MHz f_{T} ____ ____ f = 100MHzOutput Capacitance Cobo 30 pF $V_{CB} = 10V$, f = 1MHz

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

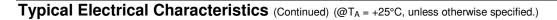


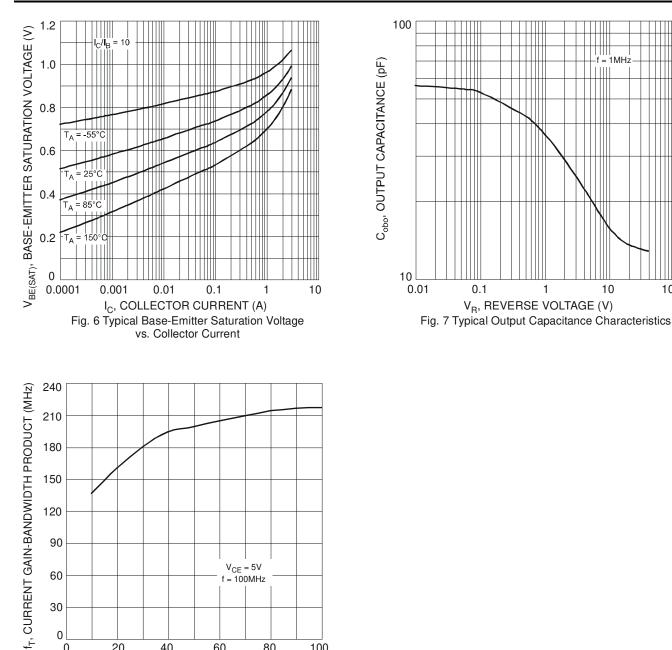


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



100





100

 $V_{CE} = 5V$

f = 100MHz

80

60

90

60

30

0

0

20

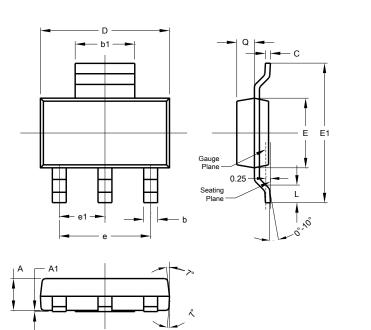
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I_C, COLLECTOR CURRENT (mA) Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current



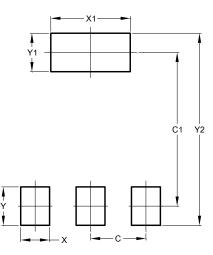
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT223				
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
E	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

SOT223

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